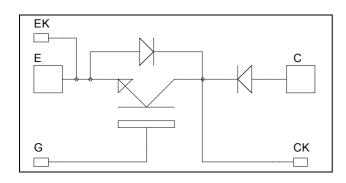


Single Switch with Series diodes NPT IGBT Power Module

 $V_{CES} = 1200V$ $I_{C} = 200A$ @ Tc = 80°C



Application

• Zero Current Switching resonant mode

Features

- Non Punch Through (NPT) FAST IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
$I_{\rm C}$	Continuous Collector Current	$T_c = 25^{\circ}C$	275	
	Continuous Conector Current	$T_c = 80^{\circ}C$	200	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	600	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	1136	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	400A @ 1200V	

TAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Ţ	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25$ °C			500	1
I_{CES}	Zero Gate voltage Collector Current	$V_{CE} = 1200V$	$T_j = 125$ °C			750	μΑ
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		3.2	3.7	V
		$I_C = 200A \qquad T_j = 1$	$T_j = 125$ °C		4.0		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 4mA$		4.5		6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$				±300	nA

Dynamic Characteristics

•	Characteristic	Test Condition	ıs	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			13.8		nF
C_{oes}	Output Capacitance				1.32		
C_{res}	Reverse Transfer Capacitance	f = 1MHz			0.88		
Q_{g}	Total gate Charge	$V_{GS} = 15V$			1320		nC
Q_{ge}	Gate – Emitter Charge	$V_{Bus} = 600V$			140		
Q_{gc}	Gate – Collector Charge	$I_C = 200A$			800		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_{C} = 200A$ $R_{G} = 1.2\Omega$			35		ns
$T_{\rm r}$	Rise Time				65		
$T_{d(off)}$	Turn-off Delay Time				320		
T_{f}	Fall Time				30		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_{C} = 200A$ $R_{G} = 1.2\Omega$			35		ns
$T_{\rm r}$	Rise Time				65		
$T_{d(off)}$	Turn-off Delay Time				360		
$T_{\rm f}$	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C	_	22	_	I
E_{off}	Turn-off Switching Energy	$I_C = 200A$ $R_G = 1.2\Omega$	$T_j = 125$ °C		12.2		mJ

Series diode ratings and characteristics

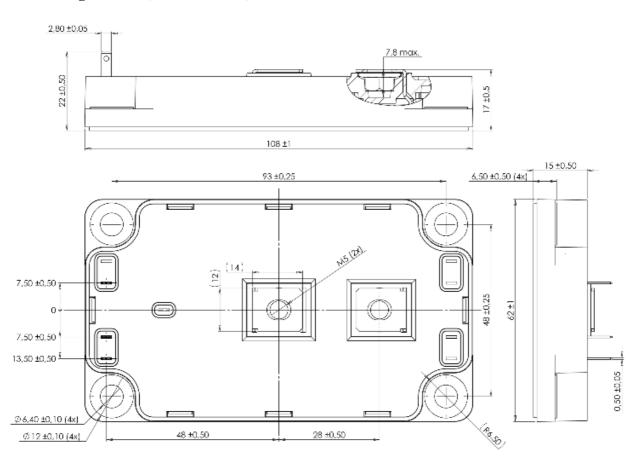
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25$ °C			750	۸
			$T_j = 125$ °C			1000	μΑ
I_F	DC Forward Current		Tc = 70°C		240		A
	Diode Forward Voltage	$I_F = 240A$			2	2.5	
$V_{\rm F}$		$I_F = 480A$			2.3		V
		$I_F = 240A$	$T_j = 125$ °C		1.8		
t _{rr}	Reverse Recovery Time	$ \begin{array}{c c} I_F = 240A & T_j = 1 \\ V_R = 800V & T_j = 1 \\ di/dt = 800A/\mu s & T_j = 2 \end{array} $	$T_j = 25$ °C		400		ns
			$T_{j} = 125^{\circ}C$		470		115
Q _{rr}	Reverse Recovery Charge		$T_j = 25$ °C		4.8		μC
			$T_{j} = 125^{\circ}C$		16		μС



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.11	°C/W
			Diode			0.23	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	18.111
Wt	Package Weight	·				300	g

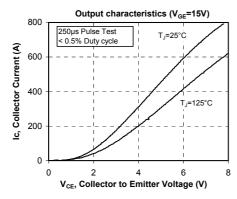
SP6 Package outline (dimensions in mm)

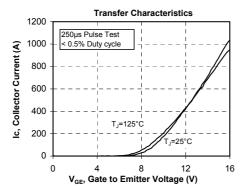


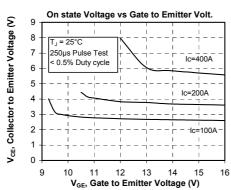
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

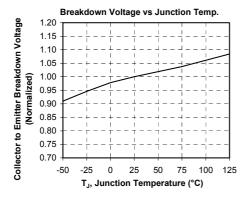


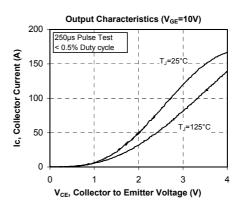
Typical Performance Curve

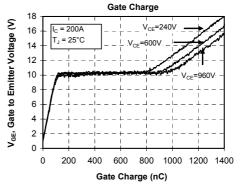


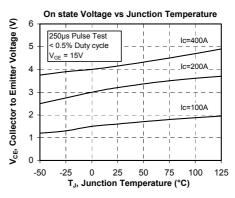


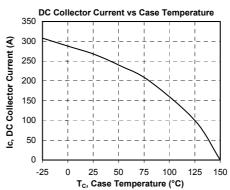




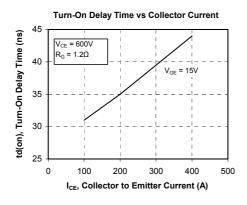


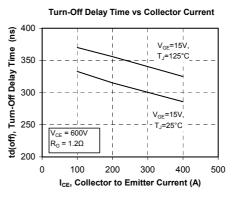


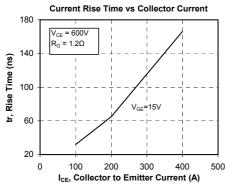


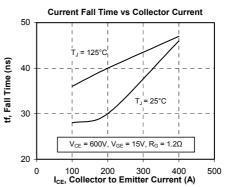


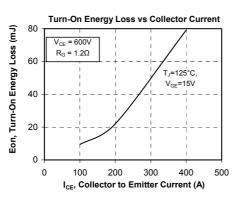


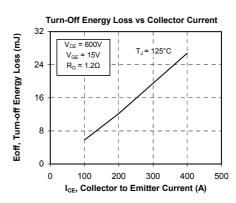


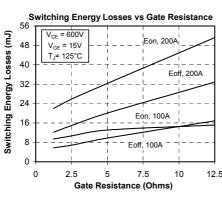


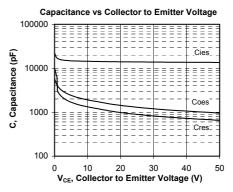






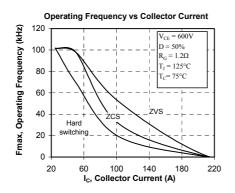


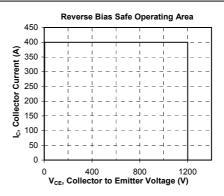


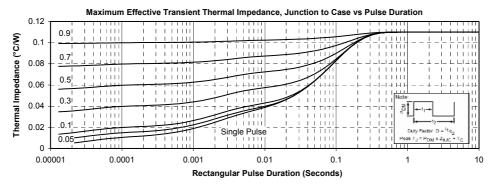


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